

THC63LVDM83C(5S)

REDUCED SWING LVDS 24Bit COLOR HOST-LCD PANEL INTERFACE

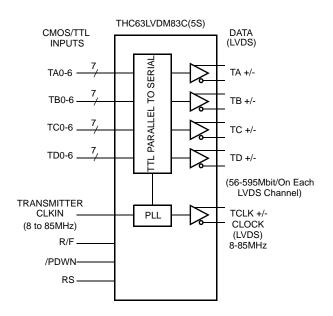
General Description

The THC63LVDM83C(5S) transmitter is designed to support pixel data transmission between Host and Flat Panel Display from NTSC up to SXGA+ resolutions. The THC63LVDM83C(5S) converts 28bits of CMOS/TTL data into LVDS(Low Voltage Differential Signaling) data stream. The transmitter can be programmed for rising edge or falling edge clocks through a dedicated pin. At a transmit clock frequency of 85MHz, 24bits of RGB data and 4bits of timing and control data (HSYNC, VSYNC, CNTL1, CNTL2) are transmitted at an effective rate of 595Mbps per LVDS channel.

Features

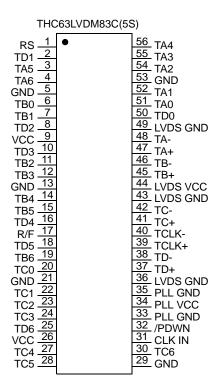
- Wide dot clock range: 8-85MHz suited for NTSC, VGA, SVGA, XGA
- PLL requires no external components
- · Supports spread spectrum clock generator
- On chip jitter filtering
- Clock edge selectable
- Supports reduced swing LVDS for low EMI
- Power down mode
- Low power single 3.3V CMOS design
- Low profile 56 Lead TSSOP Package
- 1.2 up to 3.3V tolerant data inputs to connect directly to low power,low voltage application and graphic processor.
- Backward compatible with THC63LVDM83R(24bits)

Block Diagram





Pin Out





Pin Description

Pin Name	Pin #	Туре	Description			
TA+, TA-	47, 48	LVDS OUT				
TB+, TB-	45, 46	LVDS OUT	LVDS Data Out			
TC+, TC-	41, 42	LVDS OUT	LVDS Data Out.			
TD+, TD-	37, 38	LVDS OUT				
TCLK+, TCLK-	39, 40	LVDS OUT	LVDS Clock Out.			
TA0 ~ TA6	51, 52, 54, 55, 56, 3, 4	IN				
TB0 ~ TB6	6, 7, 11, 12, 14, 15, 19	IN	Pixel Data Inputs.			
TC0 ~ TC6	20, 22, 23, 24, 27, 28, 30	IN	Fixer Data Inputs.			
TD0 ~ TD6	50, 2, 8, 10, 16, 18, 25	IN				
/PDWN	32	IN	H: Normal operation,			
,, BVIIV	02		L: Power down (all outputs are Hi-Z)			
RS	1	IN	LVDS swing mode, VREF select. RS LVDS Small Swing Input Support VCC 350mV N/A 0.6 ~ 1.4V 350mV RS=VREFa GND 200mV N/A a. VREF is Input Reference Voltage.			
R/F	17	IN	Input Clock Triggering Edge Select. H: Rising edge, L: Falling edge			
VCC	9, 26	Power	Power Supply Pins for TTL inputs and digital circuitry.			
CLKIN	31	IN	Clock in.			
GND	5, 13, 21, 29, 53	Ground	Ground Pins for TTL inputs and digital circuitry.			
LVDS VCC	44	Power	Power Supply Pins for LVDS Outputs.			
LVDS GND	36, 43, 49	Ground	Ground Pins for LVDS Outputs.			
PLL VCC	34	Power	Power Supply Pin for PLL circuitry.			
PLL GND	33, 35	Ground	Ground Pins for PLL circuitry.			



Absolute Maximum Ratings ¹

Supply Voltage (V _{CC})	-0.3V ~ +4.0V
CMOS/TTL Input Voltage	-0.3V ~ (V _{CC} + 0.3V)
CMOS/TTL Output Voltage	-0.3V ~ (V _{CC} + 0.3V)
LVDS Driver Output Voltage	-0.3V ~ (V _{CC} + 0.3V)
Output Current	continuous
Junction Temperature	+125°C
Storage Temperature Range	-55°C ~ +150°C
Resistance to soldering heat	+260°C/10sec
Maximum Power Dissipation @+25°C	0.5W

Recommended Operating Conditions

Parameter	Min	Тур	Max	Units
All Supply Voltage	3.0	3.3	3.6	V
Operating Ambient Temperature	-40		85	°C
CLK IN Frequency	8		85	MHz

^{1. &}quot;Absolute Maximum Ratings" are those valued beyond which the safety of the device can not be guaranteed. They are not meant to imply that the device should be operated at these limits. The tables of "Electrical Characteristics" specify conditions for device operation.



Electrical Characteristics

CMOS/TTL DC Specifications

 $V_{CC} = VCC = PLL \ VCC = LVDS \ VCC$

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
V _{IH}	High Level Input Voltage	RS=VCC or GND	2.0		V _{CC}	V
V _{IL}	Low Level Input Voltage	RS=VCC or GND	GND		0.8	V
V _{DDQ} ¹	Small Swing Voltage		1.2		2.8	V
V _{REF}	Input Reference Voltage	Small Swing (RS=V _{DDQ} /2)		V _{DDQ} /2		
V _{SH} ²	Small Swing High Level Input Voltage	$V_{REF} = V_{DDQ}/2$	V _{DDQ} /2 +100mV			V
V _{SL} ²	Small Swing Low Level Input Voltage	$V_{REF} = V_{DDQ}/2$			V _{DDQ} /2 -100mV	V
I _{INC}	Input Current	$0V \le V_{IN} \le V_{CC}$			±10	uA

Notes: $^1V_{DDQ}$ voltage defines max voltage of small swing input. It is not an actual input voltage. 2 Small swing signal is applied to TA0-6,TB0-6,TC0-6,TD0-6 and CLKIN.

LVDS Transmitter DC Specifications

 $V_{CC} = VCC = PLL VCC = LVDS VCC$

Symbol	Parameter	Cond	itions	Min.	Тур.	Max.	Units
VOD	Differential Output Voltage	RL=100Ω	Normal swing RS=V _{CC}	250	350	500	mV
			Reduced swing RS=GND	100	200	300	mV
ΔVOD	Change in VOD between complementary output states					35	mV
VOC	Common Mode Voltage	RL=100Ω		1.125	1.25	1.375	V
ΔVOC	Change in VOC between complementary output states					35	mV
Ios	Output Short Circuit Current	VOUT=0V, RL=100 Ω				-24	mA
I _{OZ}	Output TDI CTATE Current	/PDWN=0V,				±10	uA
	Output TRI-STATE Current	V_{OUT} =0V to V_{CC}					uA

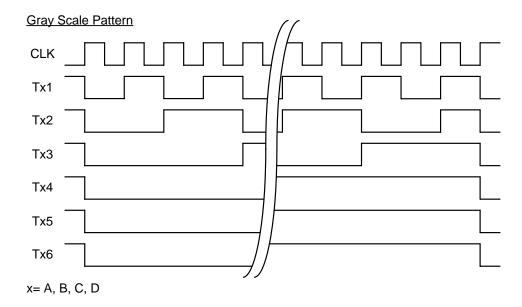




Supply Current

 $V_{CC} = VCC = PLL \ VCC = LVDS \ VCC$

Symbol	Parameter	Condition(*)		Тур.	Max.	Units
I _{TCCG}	Transmitter Supply Current	RL=100 Ω ,CL=5pF	RS=V _{CC}	52	58	mA
		V _{CC} =3.3V, f=85MHz	RS=GND	40	46	mA
		Gray Scale Pattern	K3=GND			
I _{TCCW}	Transmitter Supply Current	RL=100 Ω ,CL=5pF	RS=V _{CC}	61	67	mA
		V _{CC} =3.3V, f=85MHz	RS=GND	50	56	mA
		Worst Case Pattern	K3=GND			IIIA
I _{TCCS}	Transmitter Power Down Supply Current	/PDWN = L			10	uA



Worst Case Pattern

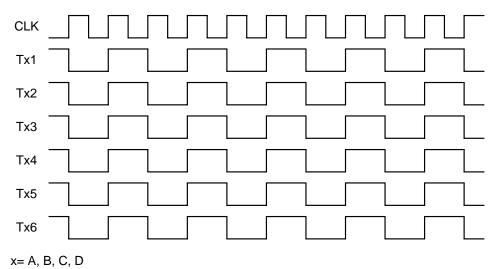


Fig1. Data Pattern





Switching Characteristics

 $V_{CC} = VCC = PLL \ VCC = LVDS \ VCC$

Symbol	Parameter	Min.	Тур.	Max.	Units
t _{TCIT}	CLK IN Transition time			5.0	ns
t _{TCP}	CLK IN Period	11.7	Т	125	ns
t _{TCH}	CLK IN High Time	0.35T	0.5T	0.65T	ns
t _{TCL}	CLK IN Low Time	0.35T	0.5T	0.65T	ns
t _{TCD}	CLK IN to TCLK+/- Delay		3T		ns
t _{TS}	TTL Data Setup to CLK IN	2.5			ns
t _{TH}	TTL Data Hold from CLK IN	0			ns
t _{LVT}	LVDS Transition Time		0.6	1.5	ns
t _{TOP1}	Output Data Position0 (T=11.7ns)	-0.2	0.0	+0.2	ns
t _{TOP0}	Output Data Position1 (T=11.7ns)	$\frac{T}{7} - 0.2$	<u>T</u> 7	$\frac{T}{7}$ + 0.2	ns
t _{TOP6}	Output Data Position2 (T=11.7ns)	$2\frac{T}{7} - 0.2$	$2\frac{T}{7}$	$2\frac{T}{7} + 0.2$	ns
t _{TOP5}	Output Data Position3(T=11.7ns)	$3\frac{T}{7} - 0.2$	3 T	$3\frac{T}{7} + 0.2$	ns
t _{TOP4}	Output Data Position4 (T=11.7ns)	$4\frac{T}{7} - 0.2$	4 T 7	$4\frac{T}{7} + 0.2$	ns
t _{TOP3}	Output Data Position5 (T=11.7ns)	$5\frac{T}{7} - 0.2$	5 T	$5\frac{T}{7} + 0.2$	ns
t _{TOP2}	Output Data Position6 (T=11.7ns)	$6\frac{T}{7} - 0.2$	6 T 7	$6\frac{T}{7} + 0.2$	ns
t _{TPLL}	Phase Lock Loop Set			10.0	ms

AC Timing Diagrams TTL Input

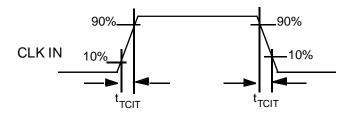


Fig2. CLKIN Transition Time

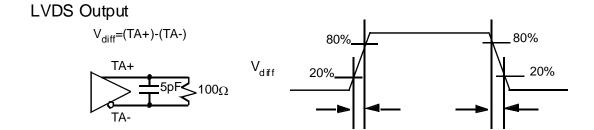
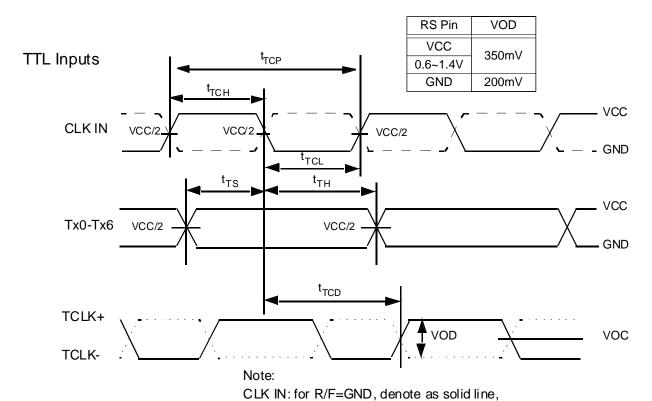


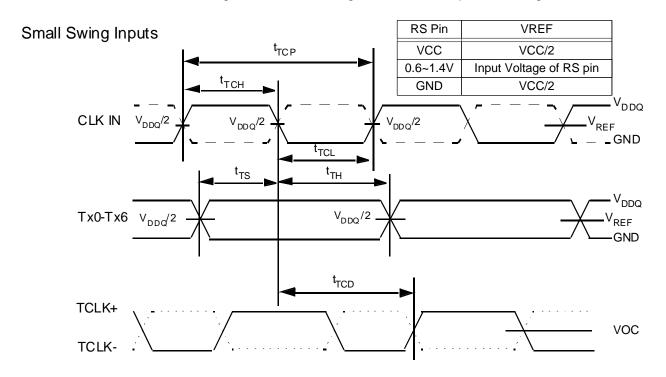
Fig3. LVDS Output Load and Transition Time

LVDS Output Load





for R/F=VCC, denote as dashed line.
Fig4. CLKIN Period, High/Low Time, Setup/Hold Timing



Note:

CLK IN: for R/F=GND, denote as solid line, for R/F=VCC, denote as dashed line.

Fig5. Small Swing Inputs





AC Timing Diagrams

LVDS Output

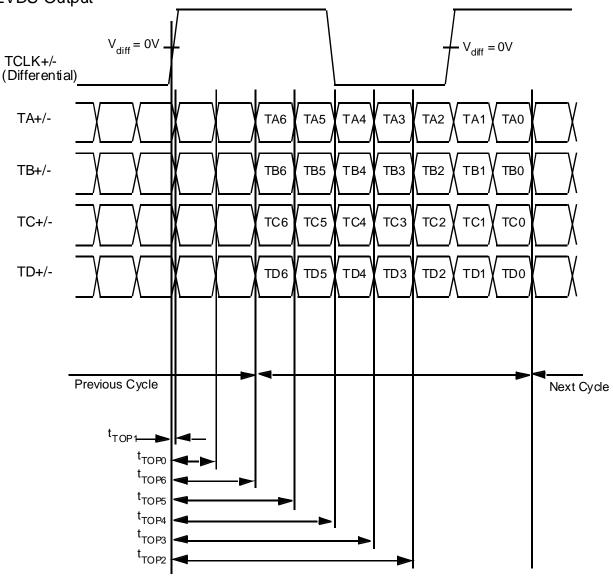
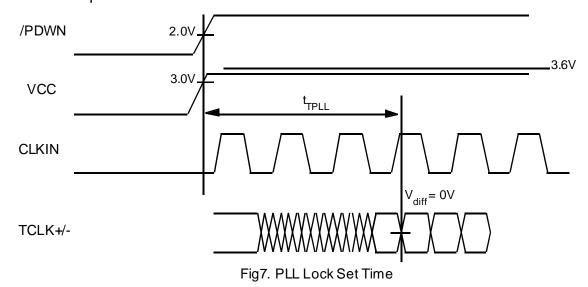


Fig6. LVDS Output Data Position

Phase Lock Loop Set Time





Note

1)Cable Connection and Disconnection

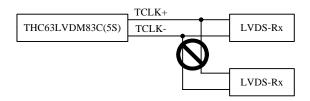
Don't connect and disconnect the LVDS cable, when the power is supplied to the system.

2)GND Connection

Connect the each GND of the PCB which THC63LVDM83C(5S) and LVDS-Rx on it. It is better for EMI reduction to place GND cable as close to LVDS cable as possible.

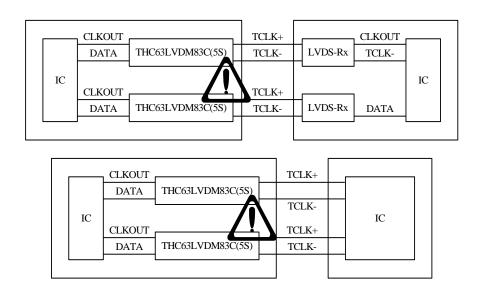
3) Multi Drop Connection

Multi drop connection is not recommended.



4) Asynchronous use

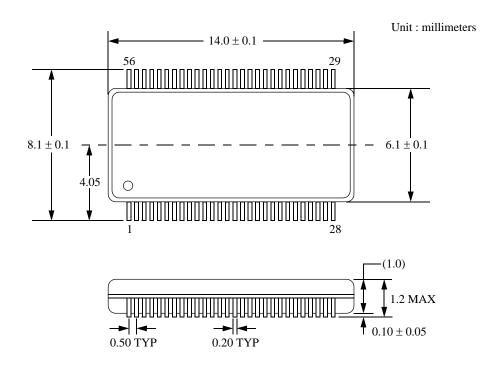
Asynchronous use such as following systems are not recommended.





Package

56 Lead Molded Thin Shrink Small Outline Package, JEDEC







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THine Electronics, Inc. E-mail: sales@thine.co.jp